

# P6SMB-E Series









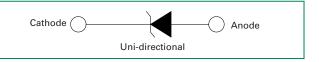
## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at $T_A$ =25°C by 10/1000 $\mu$ s Waveform (Fig.2)(Note 1), (Note 2)	P <sub>PPM</sub>	600	W
Power Dissipation on Infinite Heat Sink at $T_L$ =50°C	P <sub>D</sub>	5.0	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I <sub>FSM</sub>	100	А
Maximum Instantaneous Forward Voltage at 50A for Unidirectional Only	V <sub>F</sub>	3.5	V
Operating Temperature Range	T <sub>J</sub>	-65 to 150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R <sub>eJL</sub>	20	°C/W
Typical Thermal Resistance Junction to Ambient	R <sub>eJA</sub>	100	°C/W

#### Notes:

- 1. Non-repetitive current pulse , per Fig. 4 and derated above  $T_{_{\rm I}}$  (initial) =25°C per Fig. 3.
- 2. Mounted on copper pad area of 0.2x0.2" (5.0 x 5.0mm) to each terminal.
- 3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum

### **Functional Diagram**



### **Description**

The P6SMB-E series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

### **Features**

- Excellent clamping capability
- Low incremental surge resistance
- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC-61000-4-2 ESD 30kV(Air), 30kV (Contact)
- ESD protection of data lines in accordance with IEC 61000-4-2
- EFT protection of data lines in accordance with IEC 61000-4-4
- Built-in strain relief
- Fast response time: typically less than 1.0ps from 0V to BV min

- 600W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycles):0.01%
- High temperature to reflow soldering guaranteed: 260°C/40sec
- V<sub>BR</sub> @ T<sub>J</sub>= V<sub>BR</sub>@25°C  $\times (1 + \alpha T \times (T_1 - 25))$ (a T:Temperature Coefficient, typical value is 0.1%)
- EPI silicon technology
- Meet MSL level1, per J-STD-020C, LF maximun peak of 260°C
- Matte tin lead–free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

### **Applications**

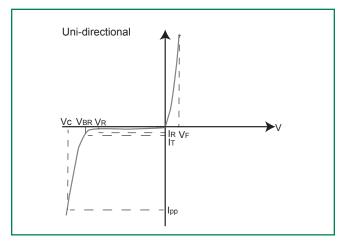
TVS devices are ideal for the protection of I/O Interfaces, V<sub>cc</sub> bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

### Electrical Characteristics (T<sub>a</sub>=25°C unless otherwise noted)

Part Number (Uni)	Reverse Stand off Voltage V <sub>R</sub>		Breakdown Voltage V <sub>BR</sub> (Volts) @ I <sub>T</sub>		Test Current I <sub>T</sub>	Maximum Clamping Voltage V <sub>c</sub> @	Maximum Peak Pulse Current I <sub>pp</sub>	Maximum Reverse Leakage I <sub>R</sub> @ V <sub>S</sub>
(=,		(Volts)	MIN	MAX	(mA)	(V)	(A) ··	(μΑ)
P6SMB350A-E	350S	300	332.0	368.0	1	482.0	1.30	1
P6SMB400A-E	400S	342	380.0	420.0	1	548.0	1.10	1
P6SMB440A-E	440S	376	418.0	462.0	1	602.0	1.00	1
P6SMB480A-E*	480S	408	456.0	504.0	1	658.0	0.95	1
P6SMB510A-E*	510S	434	485.0	535.0	1	698.0	0.86	1
P6SMB530A-E*	530S	451	503.5	556.5	1	725.0	0.83	1
P6SMB540A-E*	540S	460	513.0	567.0	1	740.0	0.82	1
P6SMB550A-E*	550S	468	522.5	577.5	1	760.0	0.79	1
P6SMB600A-E*	600S	510	570.0	630.0	1	822.0	0.73	1
P6SMB650A-E*	650S	553	617.5	682.5	1	891.0	0.68	1
P6SMB700A-E*	700S	595	665.0	735.0	1	959.0	0.63	1
P6SMB800A-E*	800S	680	760.0	840.0	1	1096.0	0.55	1
P6SMB900A-E*	900S	765	855.0	945.0	1	1233.0	0.50	1
P6SMB1000A-E*	1000S	850	950.0	1050.0	1	1365.0	0.44	1

Note: for parts with \* are still under development

### **I-V Curve Characteristics**



- P<sub>PPM</sub> Peak Pulse Power Dissipation Max power dissipation
- $V_{_{R}}$  Stand-off Voltage -- Maximum voltage that can be applied to the TVS without operation
- V<sub>ss</sub> Breakdown Voltage Maximum voltage that flows though the TVS at a specified test current (I<sub>1</sub>)
- $V_c$  Clamping Voltage Peak voltage measured across the TVS at a specified Ippm (peak impulse current)
- I<sub>R</sub> Reverse Leakage Current -- Current measured at V<sub>R</sub>
- V<sub>F</sub> Forward Voltage Drop for Uni-directional



Ratings and Characteristic Curves (T<sub>A</sub>=25°C unless otherwise noted)

Figure 1 - TVS Transients Clamping Waveform

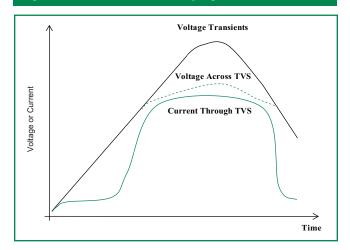


Figure 2 - Peak Pulse Power Rating

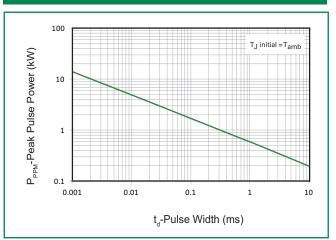


Figure 3 - Peak Pulse Power Derating Curve

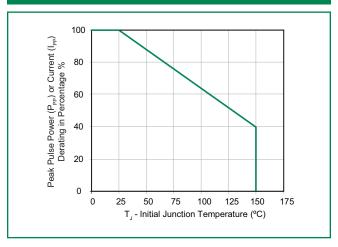


Figure 4 - Pulse Waveform

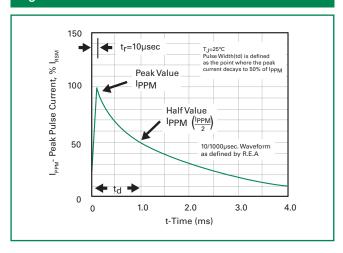


Figure 5 - Typical Junction Capacitance

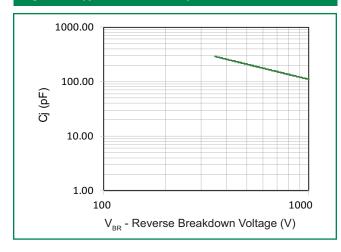


Figure 6 - Typical Transient Thermal Impedance

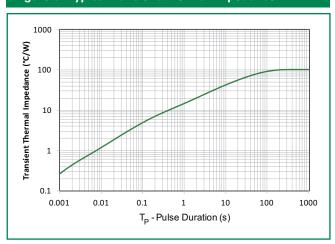




Figure 7 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Only

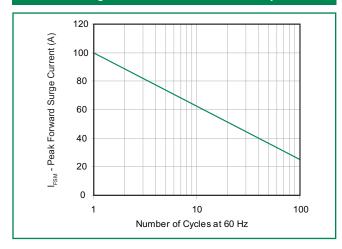
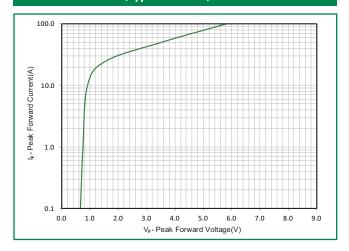


Figure 8 - Peak Forward Voltage Drop vs Peak Forward Current (Typical Values)

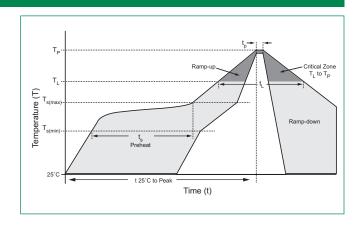


## **Soldering Parameters**

Reflow Co	ndition	Lead-free assembly	
Pre Heat	-Temperature Min (T <sub>s(min)</sub> )	150°C	
	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ra to peak	mp up rate (Liquidus Temp (T <sub>A</sub> )	3°C/second max	
T <sub>S(max)</sub> to T <sub>A</sub>	- Ramp-up Rate	3°C/second max	
Reflow	-Temperature (T <sub>A</sub> ) (Liquidus)	217°C	
nellow	-Time (min to max) (t <sub>s</sub> )	60 – 150 seconds	
Peak Temp	erature (T <sub>P</sub> )	260 <sup>+0/-5</sup> °C	
Time withi Temperatu	n 5°C of actual peak re (t <sub>p</sub> )	20 - 40 seconds	
Ramp-dow	n Rate	6°C/second max	
Time 25°C	to peak Temperature (T <sub>P</sub> )	8 minutes Max.	
Do not exc	eed	260°C	



Weight	0.003 ounce, 0.093 grams		
Case	JEDEC DO214AA. Molded plastic body over glass passivated junction		
Polarity	Color band denotes cathode except Bidirectional		
Terminal	Matte Tin-plated leads, Solderable per JESD22-B102		



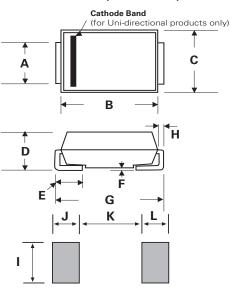
## **Environmental Specifications**

High Temp. Storage	JESD22-A103
нткв	JESD22-A108
Temperature Cycling	JESD22-A104
MSL	JEDEC-J-STD-020, Level 1
H3TRB	JESD22-A101
RSH	JESD22-A111



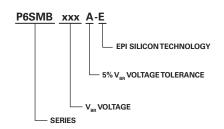
### **Dimensions**

### DO-214AA (SMB J-Bend)

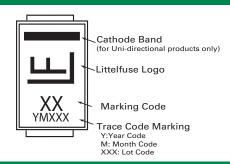


Dimensions	Inc	hes	Millimeters		
	Min	Max	Min	Max	
А	0.076	0.086	1.930	2.200	
В	0.160	0.187	4.060	4.750	
С	0.130	0.155	3.300	3.940	
D	0.078	0.103	1.990	2.610	
E	0.030	0.060	0.760	1.520	
F	-	0.008	-	0.203	
G	0.205	0.220	5.210	5.590	
Н	0.006	0.012	0.152	0.305	
1	0.089	-	2.260	-	
J	0.085	-	2.160	-	
K	-	0.107	-	2.740	
L	0.085	-	2.160	-	

### **Part Numbering System**



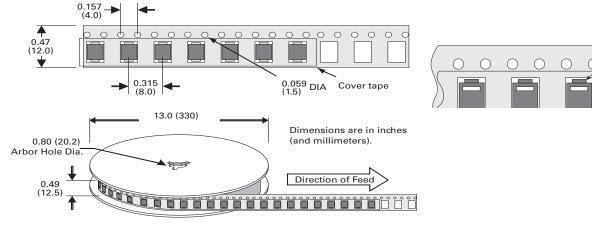
## **Part Marking System**



### **Packaging**

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
P6SMBxxxA-E	DO-214AA	3000	Tape & Reel - 12mm tape/13" reel	EIA STD RS-481

## **Tape and Reel Specification**



Cathode